NSN 5962-01-308-6355

Memory Microcircuit - Page 1 of 1



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Body Length:
Between 1.045 inches and 1.110 inches
Body Width:
Between 0.360 inches and 0.405 inches
Body Height:
Between 0.080 inches and 0.205 inches
Maximum Power Dissipation Rating:
925.0 milliwatts
Operating Tempurature Range:
+0.0/+75.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Hermetically sealed and programmable and bipolar and w/enable and schottky
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
12 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.0 volts power source
Time Rating Per Chacteristic:
40.00 nanoseconds propagation delay time, low to high level output and 40.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type:
Rom
Terminal Type And Quantity:
22 printed circuit
Shelf Life:
N/a
Unit Of Measure:

Demilitarization:
Yes - demil/mli
Fiig:
A458a0